

High-energy photoelectron spectroscopy of AlN with Cr $\mathbf{K}\alpha$ excitation

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HAXPES of AIN with Cr K α excitation

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Aluminum nitride was analyzed by high-energy photoelectron spectroscopy (HAXPES) using monochromatic Cr Kα (5414.8 eV) radiation. The reported data include a survey spectrum and high-resolution spectra of Al 1s, Al 2s, Al 2p, N 1s, O 1s and C 1s core-levels.

Keywords: AlN, HAXPES, Cr Ka

Accession#: 01711 Technique: XPS Host Material: AIN

Instrument: ULVAC-PHI

Quantes

Major Elements in Spectra: Al, N

Minor Elements in Spectra: O, C

Published Spectra: 7 Spectra in Electronic

Record: 7

Spectral Category:

comparison

INTRODUCTION

Aluminum nitride is a material of interest for packaging applications thanks to its high thermal conductivity and low thermal expansion coefficient. Its wide band gap (6.2 eV) allows it to be used as an insulating film in electronic devices.

In this work, we analyzed a thick AlN sample using a spectrometer equipped with a lab-based HAXPES monochromatic Cr Kα (5414.8 eV) source. We provide a survey scan and high-resolution spectra of Al 1s, Al 2s, Al 2p, N 1s, O 1s and C 1s regions which can serve as comparison.

SPECIMEN DESCRIPTION (ACCESSION # 01711)

Host Material: AIN

CAS Registry #: 24304-00-5

Host Material Characteristics: Homogeneous; polycrystalline; dielectric; inorganic compound; Ceramic

Chemical Name: Aluminum nitride

Source: Goodfellow Host Composition: AlN Form: Polycrystalline solid Structure: Hexagonal

History & Significance: Air exposed AlN sheet As Received Condition: 1 mm thick AlN sheet **Analyzed Region:** Same as host material

Ex Situ Preparation/Mounting: The sample was mounted on the sample holder using double sided conductive tape.

In Situ Preparation: The sample was sputter cleaned by lowenergy Ar⁺ ions (100 eV) for one hour prior to measurements to remove carbon and oxygen contamination.

Charge Control: Low-energy electrons (1 eV, filament 1.1 A)

and low-energy Ar⁺ ions (10 eV) Temp. During Analysis: 300 K Pressure During Analysis: < 3.10⁻⁷ Pa **Pre-analysis Beam Exposure:** 0 s. INSTRUMENT DESCRIPTION

Manufacturer and Model: ULVAC-PHI Quantes

Analyzer Type: spherical sector **Detector:** multichannel resistive plate **Number of Detector Elements: 32**

INSTRUMENT PARAMETERS COMMON TO ALL **SPECTRA**

■Spectrometer

Analyzer Mode: constant pass energy

Throughput (T=EN): The energy dependence can be modeled using the following equation: $\frac{A}{E_p} = (\frac{a^2}{a^2 + R^2})^b$, where a and b are constants, Ep is the pass energy, A is the peak area and R is the retard ratio equal to E/E_p, where E is the kinetic energy. Three spectral regions are recorded on a sputter cleaned sample at different pass energies. The values of a and b are then determined by a linear least square fit of the data applying the equation described above.

Excitation Source Window: Al

Excitation Source: Cr K_{α} monochromatic

Source Energy: 5414.8 eV Source Strength: 50 W

Source Beam Size: $100 \mu m \times 100 \mu m$ Signal Mode: multichannel direct

■ Geometry

Incident Angle: 22 °

Source-to-Analyzer Angle: 46 °

Emission Angle: 45 °

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Specimen Azimuthal Angle: 0 °

Acceptance Angle from Analyzer Axis: 0 °

Analyzer Angular Acceptance Width: 20 $^{\circ} \times$ 20 $^{\circ}$

■Ion Gun

Manufacturer and Model: ULVAC-PHI Quantes

Energy: 10 and 100 eV Current: 1.4×10^{-5} mA

Current Measurement Method: Faraday cup

Sputtering Species: Ar

Spot Size (unrastered): $100 \mu m$

Raster Size: N/A Incident Angle: 45 ° Polar Angle: 45 ° Azimuthal Angle: 45 °

Comment: Differentially pumped ion gun used for presputtering of the sample and to prevent reoxidation during the XPS analysis.

DATA ANALYSIS METHOD

Energy Scale Correction: The decrease of photoionization cross sections in HAXPES leads to a very low C 1s intensity. Therefore, the binding energy was referenced to the Al 2p binding energy position measured with Al K α radiation after shifting the C 1s peak to 284.8 eV. Doing so, the Al 2p binding energy was 73.4 eV. The spectra recorded with the Cr K α source were then rescaled by shifting the Al 2p to 73.4 eV.

Recommended Energy Scale Shift: 1.6 eV for binding energy

Peak Shape and Background Method: Shirley background was employed for peak area determination. No curve fitting was performed on the spectra.

Quantitation Method: PHI Multipak software Version 9.9.0.8 was used to perform quantification. Empirically determined sensitivity factors (RSFs) were provided by the software. The RSFs were derived from the pure-element relative sensitivity factor as defined in ISO 18118:2015 which were measured on pure element samples using a Cr K α source. They therefore account for the decrease of cross-section and different escape depth of photoelectrons using higher energy photons. RSFs are reported proportional to the RSF of F 1s equal to 1. The reported concentrations were calculated using these RSFs corrected to include the transmission function and asymmetry parameter.

ACKNOWLEDGMENTS

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DATA AVAILABILITY STATEMENT

The data that supports the findings of this study are available within the article and its supplementary material.

REFERENCES

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- 2. M.B. Trzhaskovskaya and V.G. Yarzhemsky, At. Data Nucl. Data Tables 129-130, 101280 (2019).
- 3. International Organization for Standardization 2015, Surface chemical analysis Auger electron spectroscopy and X-ray photoelectron spectroscopy Guide to the use of experimentally determined relative sensitivity factors for the quantitative analysis of homogeneous materials, ISO 18118:2015.

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SPECTRAL FEATURES TABLE								
Spectrum ID#	Element/ Transition	Peak Energy (eV)	Peak Width FWHM (eV)	Peak Area (eV x cts/s)	Sensitivity Factor	Concentration (at. %)	Peak Assignment	
01711-02	Al 1s	1560.4	2.19	14788	4.238	42.6	AIN	
01711-03	Al 2s	118.5	2.50	1072	0.369		AIN	
01711-04	Al 2p	73.4	1.96	295	0.075		AIN	
01711-05	N 1s	396.7	2.00	997	0.331	41.7	AIN	
01711-06	O 1s	531.4	2.94	556	0.589	12.8	Contamination	
01711-07	C 1s	284.8	1.33	41	0.199	2.9	Contamination	

	ANALYZER CALIBRATION TABLE						
Spectrum ID #	Element/ Transition	Peak Energy (eV)	Peak Width FWHM (eV)	Peak Area (eV x cts/s)	Sensitivity Factor	Concentration (at. %)	Peak Assignment
	Ag3d _{5/2}	368.12	0.63	114999			
	Cu2p _{3/2}	932.61	0.96	40205			
	Au4f _{7/2}	83.89	0.78	100500			

The spectra in the analyzer calibration table were recorded using Al $K\alpha$ photons.

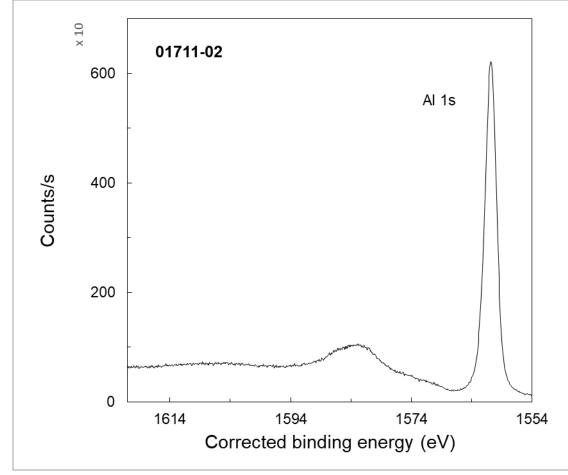
GUIDE TO FIGURES							
Spectrum (Accession) #	Spectral Region	Voltage Shift*	Multiplier	Baseline	Comment #		
01711-01	Survey	0	1	0			
01711-02	Al 1s	-1.6	1	0			
01711-03	Al 2s	-1.6	1	0			
01711-04	Al 2p	-1.6	1	0			
01711-05	N 1s	-1.6	1	0			
01711-06	O 1s	-1.6	1	0			
01711-07	C 1s	-1.6	1	0			

^{*}Voltage shift of the archived (as-measured) spectrum relative to the printed figure. The figure reflects the recommended energy scale correction due to a calibration correction, sample charging, flood gun, or other phenomenon.



160 x 100 This is the author's peer reviewed, accepted manuscript. However, the online version of record will be different from this version once it has been copyedited and typeset. PLEASE CITE THIS ARTICLE AS DOI: 10.1116/6.0001510 01711-01 140 120 Al 1s 100 Counts/s 80 Al 2p N 1s 60 2s AI KLL ₹ 40 0 1s 20 0 3000 1000 4000 2000 5000 0 Binding energy (eV) Accession # 01711-01 **Host Material** AIN XPS **Technique Spectral Region** survey Instrument **ULVAC-PHI Quantes Excitation Source** Cr Ka monochromatic **Source Energy** 5414.8 eV **Source Strength** 50 W **Source Size** 0.1 mm x 0.1 mm **Analyzer Type** spherical sector analyzer 22° **Incident Angle Emission Angle** 45° **Analyzer Pass Energy** 280 eV 2.33 eV **Analyzer Resolution Total Signal Accumulation Time** 5240 s **Total Elapsed Time** 5760 s 10 **Number of Scans Effective Detector Width** 31 eV

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■ Accession #: 01711-02 ■ Host Material: AIN ■ Technique: XPS

■ Spectral Region: Al 1s Instrument: ULVAC-PHI

Quantes

Excitation Source: Cr K_{α} monochromatic Source Energy: 5414.8 eV Source Strength: 50 W

Source Size: 0.1 mm x 0.1 mm Analyzer Type: spherical sector

Incident Angle: 22 ° Emission Angle: 45°

Analyzer Pass Energy 112 eV Analyzer Resolution: 1.17 eV **Total Signal Accumulation**

Time: 3810 s

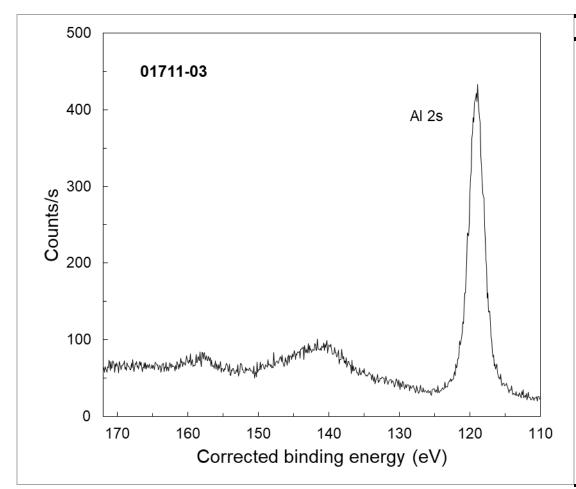
Total Elapsed Time: 4194 s

Number of Scans: 12

Effective Detector Width: 12.4







■ Host Material: AIN

■ Technique: XPS

■ Spectral Region: Al 2s

Instrument: ULVAC-PHI

Quantes

Excitation Source: $Cr K_{\alpha}$ monochromatic Source Energy: 5414.8 eV Source Strength: 50 W

Source Size: 0.1 mm x 0.1 mm

Analyzer Type: spherical sector

Incident Angle: 22 ° Emission Angle: 45 °

Analyzer Pass Energy 112 eV Analyzer Resolution: 1.17 eV

Total Signal Accumulation

Time: 3570 s

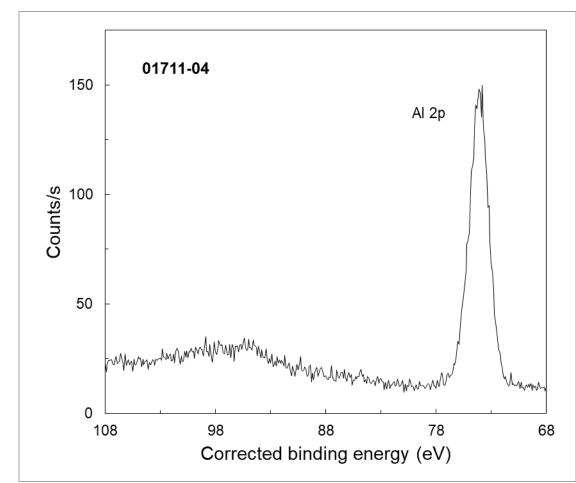
Total Elapsed Time: 3930 s

Number of Scans: 12

Effective Detector Width: 12.4







■ Host Material: AIN

■ Technique: XPS

■ Spectral Region: Al 2p

Instrument: ULVAC-PHI

Quantes

Excitation Source: $Cr K_{\alpha}$ monochromatic Source Energy: 5414.8 eV Source Strength: 50 W

Source Size: 0.1 mm x 0.1 mm

Analyzer Type: spherical sector

Incident Angle: 22 ° Emission Angle: 45 °

Analyzer Pass Energy 112 eV Analyzer Resolution: 1.17 eV Total Signal Accumulation

Time: 3774 s

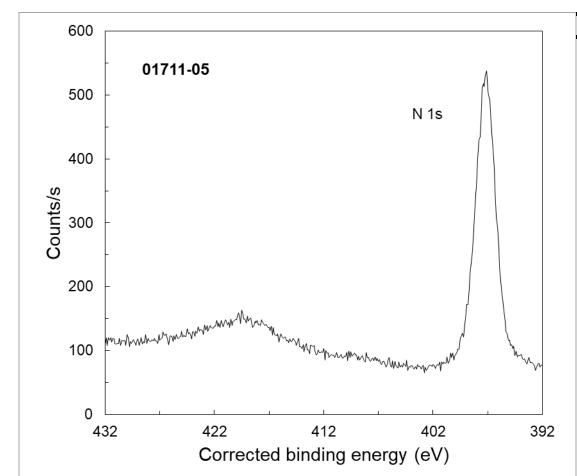
Total Elapsed Time: 4158 s

Number of Scans: 18

Effective Detector Width: 12.4







■ Host Material: AIN

■ Technique: XPS

■ Spectral Region: N 1s

Instrument: ULVAC-PHI

Quantes

Excitation Source: $Cr K_{\alpha}$ monochromatic Source Energy: 5414.8 eV Source Strength: 50 W

Source Size: 0.1 mm x 0.1 mm

Analyzer Type: spherical sector

Incident Angle: 22 ° Emission Angle: 45 °

Analyzer Pass Energy 112 eV Analyzer Resolution: 1.17 eV Total Signal Accumulation

Time: 3774 s

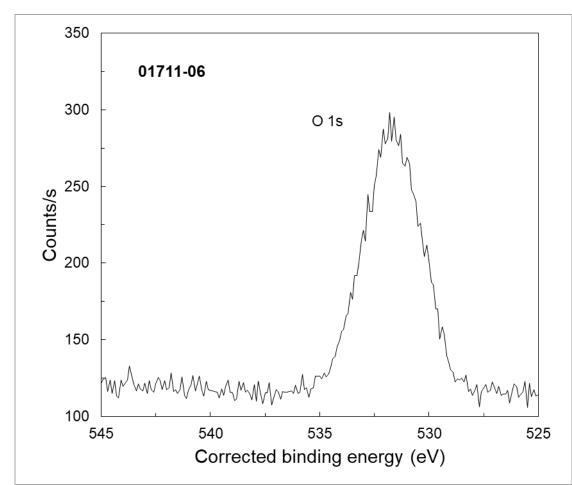
Total Elapsed Time: 4158 s

Number of Scans: 18

Effective Detector Width: 12.4







■ Host Material: AIN

■ Technique: XPS

■ Spectral Region: O 1s

Instrument: ULVAC-PHI

Quantes

Excitation Source:
Cr K_α monochromatic
Source Energy: 5414.8 eV
Source Strength: 50 W

Source Size: 0.1 mm x 0.1 mm

Analyzer Type: spherical sector

Incident Angle: 22 ° Emission Angle: 45 °

Analyzer Pass Energy 112 eV Analyzer Resolution: 1.17 eV Total Signal Accumulation

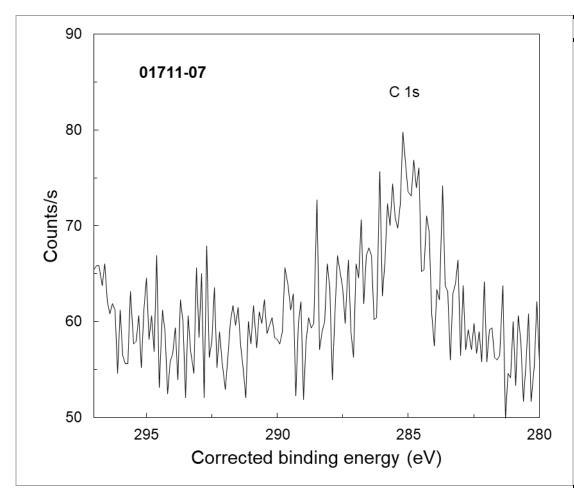
Time: 2334 s

Total Elapsed Time: 2574 s

Number of Scans: 18

Effective Detector Width: 12.4





■ Host Material: AIN
■ Technique: XPS

■ Spectral Region: C 1s

Instrument: ULVAC-PHI

Quantes

Excitation Source: $Cr K_{\alpha}$ monochromatic Source Energy: 5414.8 eV Source Strength: 50 W

Source Size: 0.1 mm x 0.1 mm

Analyzer Type: spherical sector

Incident Angle: 22 ° Emission Angle: 45 °

Analyzer Pass Energy 112 eV Analyzer Resolution: 1.17 eV Total Signal Accumulation

Time: 1554 s

Total Elapsed Time: 1716 s

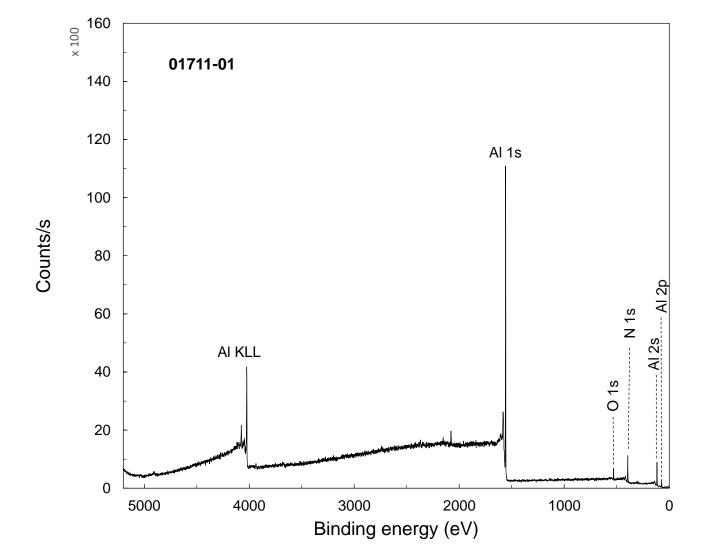
Number of Scans: 12

Effective Detector Width: 12.4



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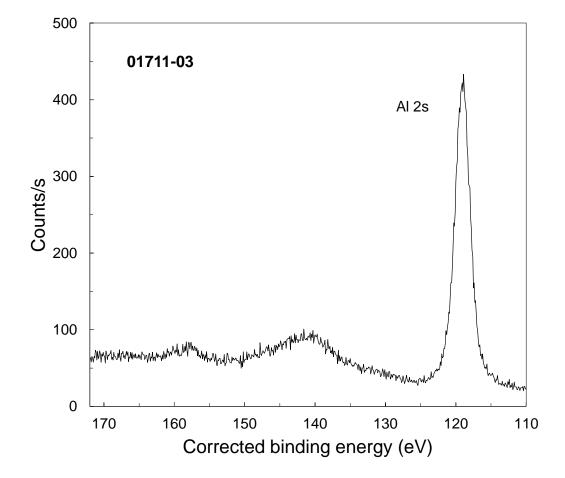
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x 10 01711-02 600 Al 1s Counts/s 400 200 0 1594 1574 1614 1554 Corrected binding energy (eV)



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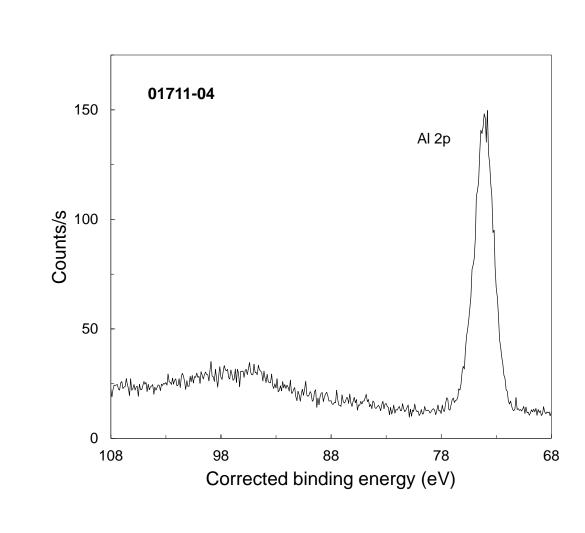
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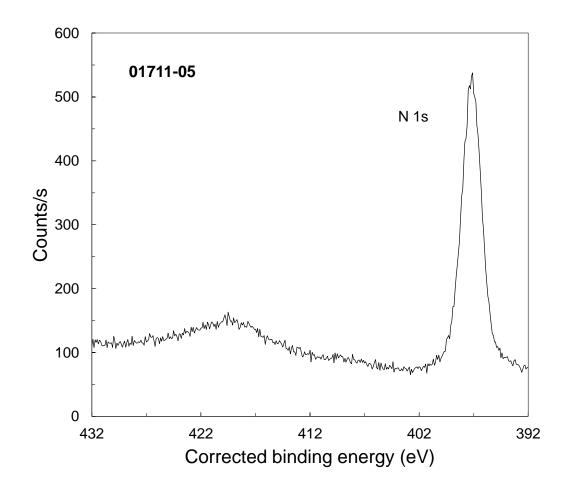
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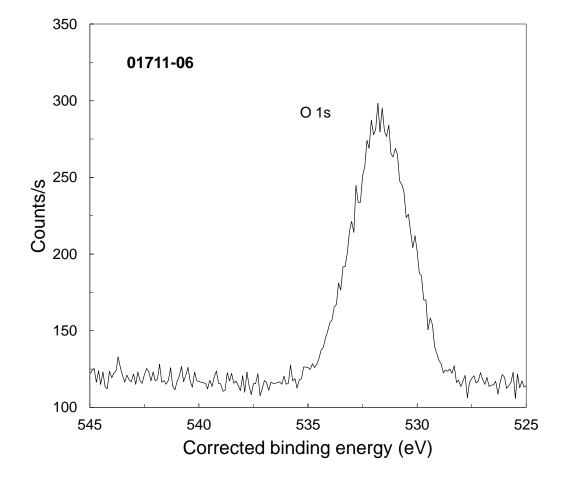
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